UNISONIC TECHNOLOGIES CO., LTD

5N60 **Power MOSFET**

5A, 600V N-CHANNEL **POWER MOSFET**

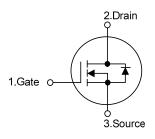
DESCRIPTION

The UTC 5N60 is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

FEATURES

- * $R_{DS(ON)}$ < 2.2 Ω @ V_{GS} =10V, I_D = 2.5A
- * Ultra Low Gate Charge (Typical 15 nC)
- * Low Reverse Transfer Capacitance (C_{RSS} = Typical 6.5 pF)
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

SYMBOL

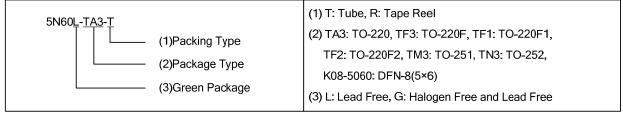


TO-220 TO-220F TO-220F1 TO-220F2 TO-220F3 TO-251 DFN-8(5x6)

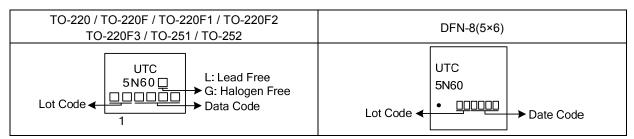
ORDERING INFORMATION

Ordering Number		Deelsene	Pin Assignment							Doolsing	
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing
5N60L-TA3-T	5N60G-TA3-T	TO-220	G	D	S	ı	ı	-	-	-	Tube
5N60L-TF1-T	5N60G-TF1-T	TO-220F1	G	D	S	ı	ı	-	-	1	Tube
5N60L-TF2-T	5N60G-TF2-T	TO-220F2	G	D	S	ı	ı	-	-	1	Tube
5N60L-TF3-T	5N60G-TF3-T	TO-220F	G	D	S	ı	ı	-	-	1	Tube
5N60L-TF3T-T	5N60G-TF3T-T	TO-220F3	G	D	S	ı	ı	-	-	1	Tube
5N60L-TM3-T	5N60G-TM3-T	TO-251	G	D	S	ı	ı	-	-	1	Tube
5N60L-TN3-R	5N60G-TN3-R	TO-252	G	D	S		-	-	-	-	Tape Reel
-	5N60G-K08-5060-R	DFN-8(5×6)	S	S	S	G	D	D	D	D	Tape Reel

Pin Assignment: G: Gate D: Drain S: Source Note:



■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	600	V
Gate-Source Voltage		V_{GSS}	±30	V
Avalanche Current (Note 2)		I _{AR}	5	Α
Continuous Drain Current		I_D	5	Α
Pulsed Drain Current (Note 2)		I _{DM}	20	Α
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	210	1
	Repetitive (Note 2)	E _{AR}	10	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
Power Dissipation	TO-220		100	
	TO-220F/TO-220F1	D	26	
	TO-220F3		36	\A/
	TO-220F2	P _D	38	W
	TO-251 / TO-252		54	
	DFN-8(5×6)		28	
Junction Temperature		TJ	+150	°C
Operation Temperature		T _{OPR}	-55 ~ +150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pulse width limited by $T_{J(\mbox{\scriptsize MAX})}$
- 3. L = 16.8mH, I_{AS} = 5A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25°C
- 4. $I_{SD} \le 5A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL DATA

PARAME	TER	SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F TO-220F1/ TO-220F2 TO-220F3	$ heta_{\sf JA}$	62.5	°C/W
	TO-251 / TO-252		160	
	DFN-8(5×6)		75	
	TO-220		1.25	
	TO-220F/TO-220F1 TO-220F3		3.47	0000
Junction to Case	TO-220F2	θις	3.28	°C/W
	TO-251 / TO-252		2.3	
	DFN-8(5×6)		4.46	

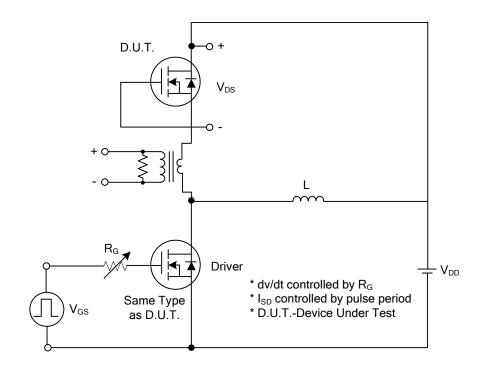
■ **ELECTRICAL CHARACTERISTICS** (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS									
Drain-Source Breakdown Voltage		BV _{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	600			V		
Drain-Source Leakage Current		I _{DSS}	V _{DS} =600V, V _{GS} = 0V			1	μA		
Coto Course Legisera Current	rward	I _{GSS}	$V_{GS} = 30V, V_{DS} = 0V$			100	A		
Gate-Source Leakage Current Re	Reverse		$V_{GS} = -30V, V_{DS} = 0V$			-100	nA		
reakdown Voltage Temperature Coefficient		$\triangle BV_{DSS}/\triangle T_{J}$	I _D =250μA, Referenced to 25℃		0.6		V/°C		
ON CHARACTERISTICS									
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V		
Static Drain-Source On-State Resista	ance	R _{DS(ON)}	$V_{GS} = 10V, I_D = 2.5A$		1.8	2.2	Ω		
DYNAMIC CHARACTERISTICS									
Input Capacitance		C_{ISS}	\\ - 25\\ \\ - 0\\		515	670	pF		
Output Capacitance		Coss	$V_{DS} = 25V, V_{GS} = 0V,$ $f = 1.0MHz$		55	72	pF		
Reverse Transfer Capacitance		C_{RSS}	1 = 1.0WH2		6.5	8.5	pF		
SWITCHING CHARACTERISTICS									
Turn-On Delay Time		$t_{D(ON)}$			10	30	ns		
Turn-On Rise Time		t _R	$V_{DD} = 300V, I_{D} = 5A,$		42	90	ns		
Turn-Off Delay Time		t _{D(OFF)}	$R_G = 25\Omega$ (Note 1, 2)		38	85	ns		
Turn-Off Fall Time		t _F			46	100	ns		
Total Gate Charge		Q_G	100) (50		15	19	nC		
Gate-Source Charge		Q_GS	$V_{DS} = 480 \text{ V}, I_{D} = 5\text{A},$		2.5		nC		
Gate-Drain Charge		Q_GD	V _{GS} = 10 V (Note 1, 2)		6.6		nC		
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS									
Drain-Source Diode Forward Voltage)	V_{SD}	$V_{GS} = 0 \text{ V}, I_{S} = 5A$			1.4	V		
Maximum Continuous Drain-Source [Diode	,				5	۸		
Forward Current		Is				5	Α		
Maximum Pulsed Drain-Source Diode		la				20	Α		
Forward Current		I _{SM}				20	^		
Reverse Recovery Time		t _{rr}	$V_{GS} = 0 \text{ V}, I_{S} = 5A,$		300		ns		
Reverse Recovery Charge		Q_{RR}	d _{IF} / dt = 100 A/µs (Note 1)		2.2		μC		

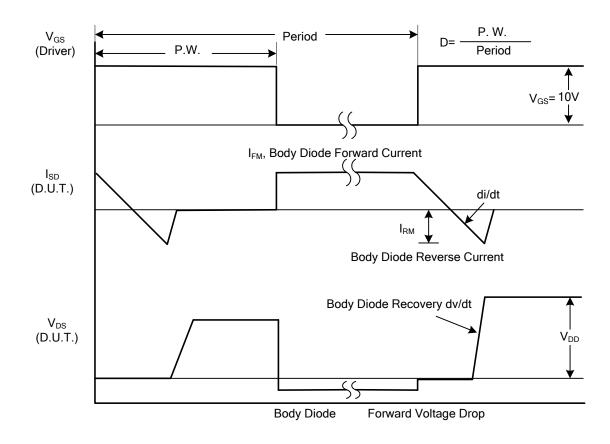
Note: 1. Pulse Test: Pulse width \leq 300 μ s, Duty cycle \leq 2%

^{2.} Essentially independent of operating temperature

■ TEST CIRCUITS AND WAVEFORMS

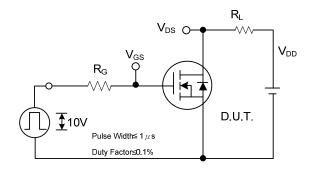


Peak Diode Recovery dv/dt Test Circuit

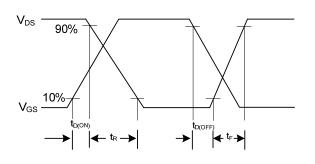


Peak Diode Recovery dv/dt Waveforms

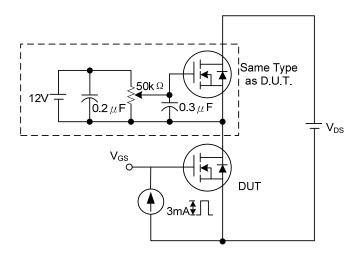
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



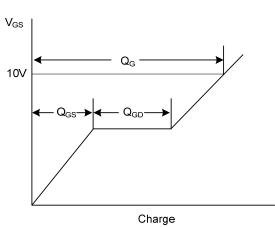
Switching Test Circuit



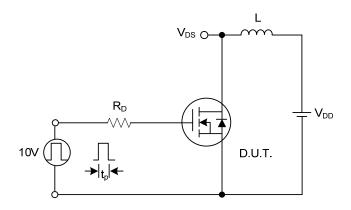
Switching Waveforms



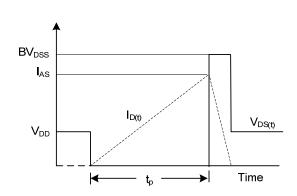
Gate Charge Test Circuit



Gate Charge Waveform

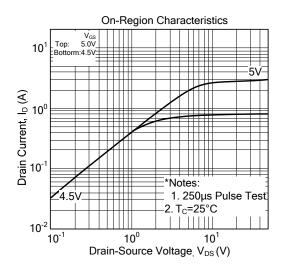


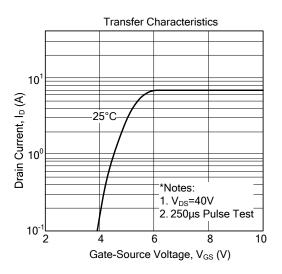
Unclamped Inductive Switching Test Circuit

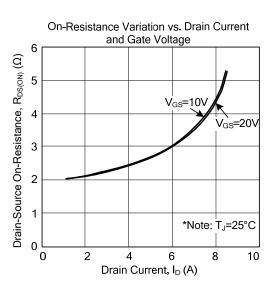


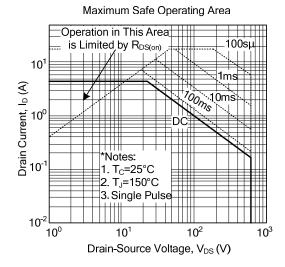
Unclamped Inductive Switching Waveforms

■ TYPICAL CHARACTERISTICS









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